# 74LVC1G32Q Single 2-Input OR Gate

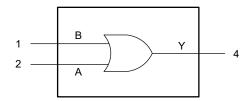
# **GENERAL DESCRIPTION**

The 74LVC1G32Q is a single 2-input OR function gate that is designed for 1.65V to 5.5V  $V_{\rm CC}$  operation. The inputs from 3.3V or 5V device make this device to operate as a translator in a mixed 3.3V and 5V system environment. All of the inputs support Schmitt trigger action, allowing slower input rise and fall time for the device.

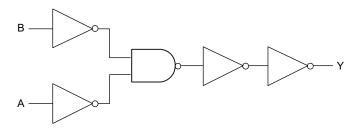
For partial power-down applications using  $I_{\text{OFF}}$ , this device is extremely suitable. When the device is powered down, the damaging current backflow will be prevented from passing through the device.

This device is AEC-Q100 qualified (Automotive Electronics Council Standard Q100 Grade 1) and the use of this device is suitable for automotive applications.

### **LOGIC SYMBOL**



# **LOGIC DIAGRAM**



## **FEATURES**

- AEC-Q100 (Grade 1) Qualified for Automotive Applications
  - T<sub>A</sub> = -40°C to +125°C
- Wide Supply Voltage Range: 1.65V to 5.5V
- Inputs Accept Voltages up to 5.5V
- +24mA/-24mA Output Current at V<sub>CC</sub> = 3.0V
- CMOS Low Power Consumption
- High Noise Immunity
- Direct Interface with TTL Levels
- Complies with JEDEC Standards:
  - JESD8-7 (1.65V to 1.95V)
  - JESD8-5 (2.3V to 2.7V)
  - JESD8-B/JESD36 (2.7V to 3.6V)
- Latch-up Performance Exceeds 250mA
- -40°C to +125°C Operating Temperature Range
- Available in a Green SC70-5 Package

### **FUNCTION TABLE**

INP	OUTPUT	
Α	АВ	
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

H = High Voltage Level

L = Low Voltage Level

# PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	TEMPERATURE		PACKAGE MARKING	PACKING OPTION	
74LVC1G32Q	SC70-5	-40°C to +125°C	74LVC1G32QC5G/TR	G6QXX	Tape and Reel, 3000	

### MARKING INFORMATION

NOTE: XX = Date Code. YYY X X Date Code - Week Date Code - Year - Serial Number

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

### ABSOLUTE MAXIMUM RATINGS (1)

ABOOLOTE III, CAIMOIII TA ATIMOO
Supply Voltage Range, V <sub>CC</sub> 0.5V to 6.5V
Input Voltage Range, V <sub>I</sub> <sup>(2)</sup> 0.5V to 6.5V
Input Clamp Current, I <sub>IK</sub> (V <sub>I</sub> < 0V)50mA
Output Clamp Current, $I_{OK}$ ( $V_O > V_{CC}$ or $V_O < 0V$ )±50mA
Output Voltage, V <sub>O</sub>
Active Mode0.5V to V <sub>CC</sub> + 0.5V
Power-Down Mode (V <sub>CC</sub> = 0V)0.5V to 6.5V
Output Current, $I_O(V_O = 0V \text{ to } V_{CC})$
Output in High-State50mA
Output in Low-State50mA
Supply Current, I <sub>CC</sub> ±100mA
Ground Current, I <sub>GND</sub> 100 mA
Junction Temperature (3)+150°C
Storage Temperature Range65°C to +150°C
Lead Temperature (Soldering, 10s)+260°C
ESD Susceptibility
HBM7000V
CDM1000V

RECOMMENDED OPERATING	CONDITIONS
Supply Voltage Range, V <sub>CC</sub>	1.65V to 5.5V
Input Voltage Range, V₁	0V to 5.5V
Output Voltage Range, V <sub>O</sub>	
Active Mode	0V to V <sub>CC</sub>
Power-Down Mode (V <sub>CC</sub> = 0V)	0V to 5.5V
Input Transition Rise and Fall Rate, $\Delta t/\Delta V$	
V <sub>CC</sub> = 1.65V to 2.7V	20ns/V (MAX)
V <sub>CC</sub> = 2.7V to 5.5V	10ns/V (MAX)
Operating Temperature Range	40°C to +125°C

### **OVERSTRESS CAUTION**

- 1. Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.
- 2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 3. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

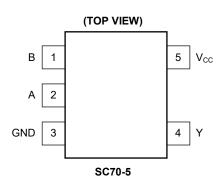
### **ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

### **DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

# **PIN CONFIGURATION**



# **PIN DESCRIPTION**

PIN	NAME	FUNCTION
1	В	Data Input.
2	Α	Data Input.
3	GND	Ground.
4	Υ	Data Output.
5	V <sub>CC</sub>	Supply Voltage.

# **ELECTRICAL CHARACTERISTICS**

(Full = -40°C to +125°C, all typical values are measured at  $V_{CC}$  = 3.3V and  $T_A$  = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL		CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
		V <sub>CC</sub> = 1.65V to 1	.95V	Full	0.65 × V <sub>CC</sub>			
High-Level Input		$V_{CC} = 2.3V \text{ to } 2.7$	7V	Full	1.7	±0.01 ±0.01 0.05 6.5		V
Voltage	V <sub>IH</sub>	$V_{CC} = 2.7V \text{ to } 3.6$	SV .	Full	2.0			V
		$V_{CC} = 4.5V \text{ to } 5.5$	5V	Full	0.7 × V <sub>CC</sub>			
		V <sub>CC</sub> = 1.65V to 1	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$					
Low-Level Input		$V_{CC} = 2.3V \text{ to } 2.7$	7V	Full			0.7	V
Voltage	V <sub>IL</sub>	$V_{CC} = 2.7V \text{ to } 3.6$	SV .	Full			0.8	V
		V <sub>CC</sub> = 4.5V to 5.5	5V	Full		±0.01 ±0.01 0.01	0.3 × V <sub>CC</sub>	
			$I_0$ = -100 $\mu$ A, $V_{CC}$ = 1.65 $V$ to 5.5 $V$	Full	V <sub>CC</sub> - 0.05	1.4 2.0 2.3		
			I <sub>O</sub> = -4mA, V <sub>CC</sub> = 1.65V	Full	1.4			
High-Level Output	V <sub>OH</sub>	\ -\\ -\\	I <sub>O</sub> = -8mA, V <sub>CC</sub> = 2.3V	Full	2.0	±0.01 ±0.01 0.01 0.05		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Voltage	Vон	V <sub>I</sub> = V <sub>IH</sub> Or V <sub>IL</sub>	I <sub>O</sub> = -12mA, V <sub>CC</sub> = 2.7V	Full	2.3			V
			I <sub>O</sub> = -24mA, V <sub>CC</sub> = 3.0V	Full	2.5	0.65 × V <sub>CC</sub> 1.7  2.0  0.7 × V <sub>CC</sub> 0.35  0  0  0  0  0  0  0  0  1.4  2.0  2.3  2.5  4.0  0.0  0.0  0.0  0.0  0.0  0.0  0		
			I <sub>O</sub> = -32mA, V <sub>CC</sub> = 4.5V	Full	4.0		0.8 0.3 × V <sub>CC</sub> 0.10 0.30 0.30 0.35 0.55 0.55  2.055  ±0.01 ±1  ±0.01 2  0.01 2  0.05 5	
			$I_{\rm O}$ = 100 $\mu$ A, $V_{\rm CC}$ = 1.65V to 5.5V	Full			0.10	
			$ \begin{array}{cccccccccccccccccccccccccccccccccccc$					
Low-Level Output	Vol	\/ = \/ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	I <sub>O</sub> = 8mA, V <sub>CC</sub> = 2.3V	Full			0.30	V
Voltage	V <sub>OL</sub>	VI - VIH OI VIL	I <sub>O</sub> = 12mA, V <sub>CC</sub> = 2.7V	Full			0.35	V
			I <sub>O</sub> = 24mA, V <sub>CC</sub> = 3.0V	Full			0.55	
			I <sub>O</sub> = 32mA, V <sub>CC</sub> = 4.5V	Full			0.35 × V <sub>CC</sub> 0.7 0.8 0.3 × V <sub>CC</sub> 0.10 0.30 0.30 0.35 0.55 0.55 20.01 ±1 20.01 2 0.05 5	
Input Leakage Current	I <sub>I</sub>	V <sub>I</sub> = 5.5V or GN	D, V <sub>CC</sub> = 0V to 5.5V	Full		±0.01	±1	μA
Power-Off Leakage Current	I <sub>OFF</sub>	$V_{CC} = 0V, V_I \text{ or } V_I$	$I_{O} = 32\text{mA}, V_{CC} = 4.5\text{V}$ = 5.5V or GND, $V_{CC} = 0\text{V to } 5.5\text{V}$ $c_{C} = 0\text{V}, V_{I} \text{ or } V_{O} = 5.5\text{V}$			±0.01	2	μA
Supply Current	I <sub>cc</sub>	V <sub>I</sub> = 5.5V or GND, I <sub>O</sub> = 0A, V <sub>CC</sub> = 1.65V to 5.5V		Full		0.01	2	μA
Additional Supply Current	ΔI <sub>CC</sub>	Per Pin, $V_{CC} = 2$ $I_0 = 0A$	.3V to 5.5V, $V_I = V_{CC} - 0.6V$ ,	Full		0.05	5	μA
Input Capacitance	Cı	$V_{CC} = 3.3V, V_{I} =$	GND to V <sub>CC</sub>	Full		6.5		pF

# **DYNAMIC CHARACTERISTICS**

(For test circuit, see Figure 1, for waveforms see Figure 2. All typical values are measured at  $T_A = +25^{\circ}\text{C}$  and  $V_{CC} = 1.8\text{V}$ , 2.5V, 2.7V, 3.3V and 5.0V respectively, unless otherwise noted.)

PARAMETER	SYMBOL	CONDI	TEMP	MIN (1)	TYP	MAX (2)	UNITS	
		A, B to Y, see Figure 2	V <sub>CC</sub> = 1.65V to 1.95V	Full	1.0	7.9	13.0	ns
	t <sub>PD</sub>		V <sub>CC</sub> = 2.3V to 2.7V	Full	0.5	4.3	7.0	
Propagation Delay (2)			V <sub>CC</sub> = 2.7V	Full	0.5	3.7	7.0	
			V <sub>CC</sub> = 3.0V to 3.6V	Full	0.5	3.4	6.0	
			V <sub>CC</sub> = 4.5V to 5.5V	Full	0.1	3.7	6.0	
Power Dissipation Capacitance (3)	$C_{PD}$	$V_I = GND$ to $V_{CC}$ , $V_{CC} =$	3.3V	+25°C		17		pF

#### NOTES:

- 1. Specified by design and characterization; not production tested.
- 2. t<sub>PD</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
- 3.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o})$$

where:

 $f_i$  = Input frequency in MHz.

f<sub>o</sub> = Output frequency in MHz.

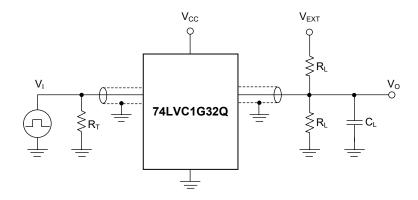
C<sub>L</sub> = Output load capacitance in pF.

 $V_{CC}$  = Supply voltage in Volts.

N = Number of inputs switching.

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{Sum of outputs.}$ 

# **TEST CIRCUIT**



Test conditions are given in Table 1.

Definitions for test circuit:

R<sub>L</sub>: Load resistance.

C<sub>L</sub>: Load capacitance (includes jig and probe).

 $R_T$ : Termination resistance (equals to output impedance  $Z_0$  of the pulse generator).

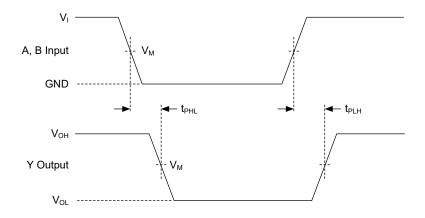
V<sub>EXT</sub>: External voltage used to measure switching time.

Figure 1. Test Circuit for Measuring Switching Times

**Table 1. Test Conditions** 

SUPPLY VOLTAGE	INI	PUT	LOAD		LOAD V <sub>EXT</sub>		V <sub>EXT</sub>
V <sub>cc</sub>	$V_{l}$	$t_R = t_F$	CL	R∟	t <sub>PLH</sub> , t <sub>PHL</sub>		
1.65V to 1.95V	$V_{CC}$	≤ 2.0ns	≤ 2.0ns 30pF 1kΩ		Open		
2.3V to 2.7V	V <sub>CC</sub>	≤ 2.0ns	30pF	500Ω	Open		
2.7V	2.7V	≤ 2.5ns	50pF	500Ω	Open		
3.0V to 3.6V	2.7V	≤ 2.5ns	50pF 500Ω		Open		
4.5V to 5.5V	V <sub>CC</sub>	≤ 2.5ns	50pF	500Ω	Open		

# **WAVEFORMS**



Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels:  $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Figure 2. Input A, B to Output Y Propagation Delays

**Table 2. Measurement Points** 

SUPPLY VOLTAGE	INPUT	OUTPUT
Vcc	V <sub>M</sub> <sup>(1)</sup>	V <sub>M</sub>
1.65V to 1.95V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>
2.3V to 2.7V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>

### NOTE:

1. The measurement points should be  $V_{IH}$  or  $V_{IL}$  when the input rising or falling time exceeds 2.5ns.

# **REVISION HISTORY**

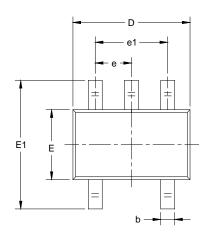
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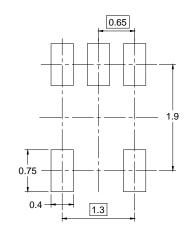
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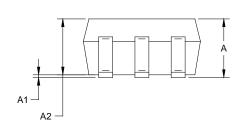
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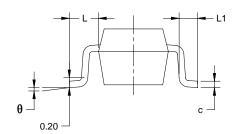
# **PACKAGE OUTLINE DIMENSIONS** SC70-5





RECOMMENDED LAND PATTERN (Unit: mm)



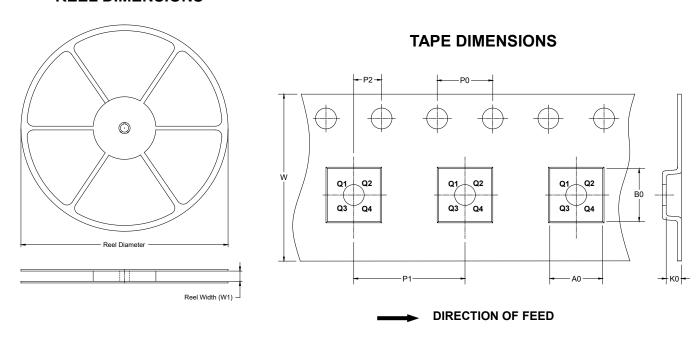


Symbol		nsions meters		nsions ches	
	MIN	MAX	MIN	MAX	
Α	0.800	1.100	0.031	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.220	0.003	0.009	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.65	TYP	0.026	S TYP	
e1	1.300 BSC		0.051 BSC		
L	0.525	REF	0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

- Body dimensions do not include mode flash or protrusion.
   This drawing is subject to change without notice.

# TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**

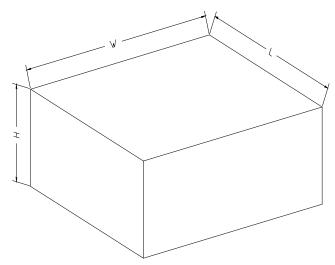


NOTE: The picture is only for reference. Please make the object as the standard.

### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SC70-5	7"	9.5	2.25	2.55	1.20	4.0	4.0	2.0	8.0	Q3

## **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

## **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18